

# GL9□08 / GL8□08 Series

20.32mm Character Height  
Numeric LEDs

■ Model No.

GL9L08/GL8L08  
GL9T08/GL8T08

Red (High-luminosity)  
Red (High-luminosity)

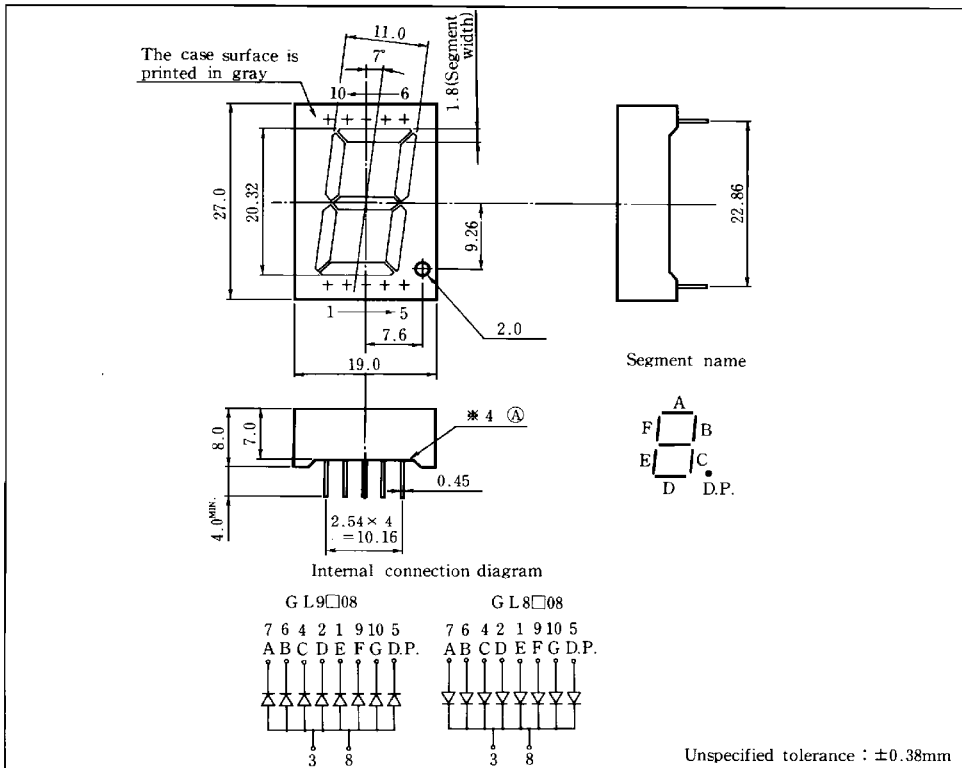
GaAlAs/GaAs  
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■ Features

1. Character height : 20.32mm
2. 1 digit
3. Case mold type
4. Diamond cut type segments

■ Outline Dimensions

(Unit: mm)



GL9□08 / GL8□08

■ Absolute Maximum Ratings

(Ta=25°C)

Parameter		Symbol	GL9L08	GL8L08				Unit	
			GL9T08	GL8T08					
Power dissipation	*1 Per digit	P	308					mW	
Continuous forward current	*1 Per digit	I <sub>F</sub>	140					mA	
	*2	I <sub>F</sub>	20					mA	
*3 Peak forward current	*2	I <sub>FM</sub>	100					mA	
Derating factor	*2 DC	—	0.36					mA/°C	
	Pulse	—	1.82					mA/°C	
Reverse voltage	Per segment	V <sub>R</sub>	5					V	
	Per decimal point	V <sub>R</sub>	5					V	
Operating temperature		T <sub>opr</sub>	-30 to +70						°C
Storage temperature		T <sub>stg</sub>	-40 to +80						°C
*4 Soldering temperature		T <sub>sold</sub>	260 (within 5 seconds)						°C

\*1 Per digit: 7 segments

\*2 Per segment, or per decimal point

\*3 Duty ratio = 1/10, Pulse width = 0.1ms

\*4 At the position of 2.6 mm from (A) level of outline dimensions

GL9L08/GL8L08(Red) , GL9T08/GL8T08(Red)

■ Electro-optical Characteristics

(Ta=25°C)

Parameter		Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	Per segment	V <sub>F</sub>	GL9L08/GL8L08	I <sub>F</sub> =10mA	—	1.7	2.2	V
			GL9T08/GL8T08	I <sub>F</sub> =10mA	—	1.7	2.2	
	Per decimal point		GL9L08/GL8L08	I <sub>F</sub> =10mA	—	1.7	2.2	V
			GL9T08/GL8T08	I <sub>F</sub> =10mA	—	1.7	2.2	
*5 Luminous intensity	Per segment	I <sub>v</sub>	GL9L08/GL8L08	I <sub>F</sub> =10mA	2.2	5.8	—	mcd
			GL9T08/GL8T08	I <sub>F</sub> =10mA	1.0	2.2	—	
	Per decimal point		GL9L08/GL8L08	I <sub>F</sub> =10mA	0.8	2.3	—	mcd
			GL9T08/GL8T08	I <sub>F</sub> =10mA	0.4	0.9	—	
*2 Peak emission wavelength		λ <sub>p</sub>	GL9L08/GL8L08	I <sub>F</sub> =10mA	—	660	—	nm
			GL9T08/GL8T08	I <sub>F</sub> =10mA	—	660	—	
*2 Spectrum radiation bandwidth		Δλ	GL9L08/GL8L08	I <sub>F</sub> =10mA	—	20	—	nm
			GL9T08/GL8T08	I <sub>F</sub> =10mA	—	20	—	
Reverse current	Per segment	I <sub>R</sub>	GL9L08/GL8L08	V <sub>R</sub> =4V	—	—	10	μA
			GL9T08/GL8T08	V <sub>R</sub> =4V	—	—	10	
	Per decimal point		GL9L08/GL8L08	V <sub>R</sub> =4V	—	—	10	μA
			GL9T08/GL8T08	V <sub>R</sub> =4V	—	—	10	
*2 Response frequency		f <sub>c</sub>	GL9L08/GL8L08	—	—	8	—	MHz
			GL9T08/GL8T08	—	—	8	—	

\*2 Per segment, or per decimal point

\*5 Tolerance: ±30%